

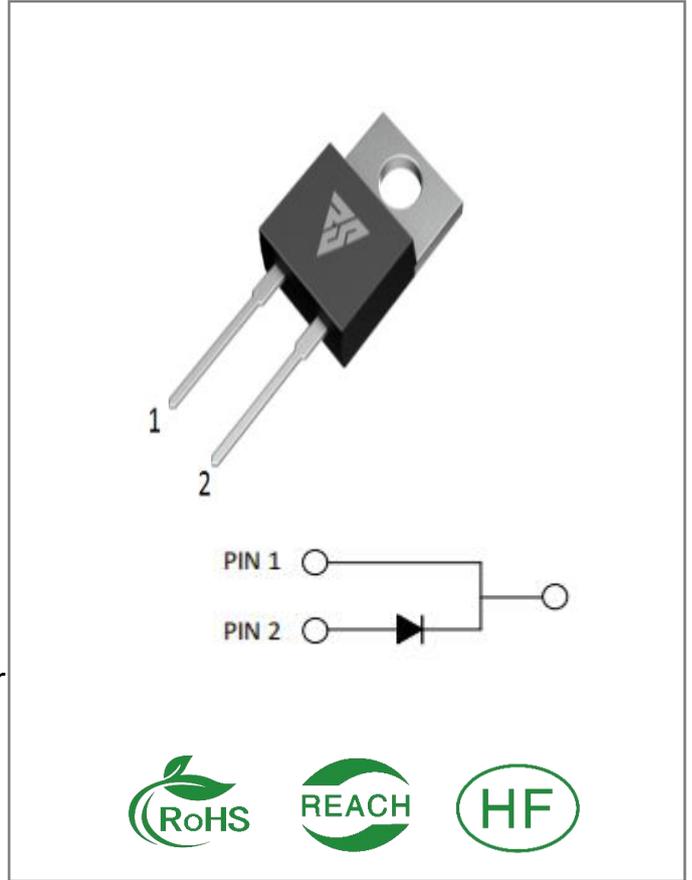
VRRM	IF (TC=150°C)	QC
650V	6A	17nC

Applications:

- Power Factor Correction
- Sever Mode Power Supplies
- Uninterruptible Power Supply

Features:

- Low Forward Voltage Drop
- High-Speed Switching
- Positive Temperature Coefficient
- Temperature-Independent Switching Behavior



Ordering Information

Part Number	Package	Marking	Packing	Qty.
RSS06065A	TO-220-2	RSS06065A	Tube	50 PCS

Maximum Ratings (T_J= 25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
VRRM	Repetitive Peak Reverse Voltage	650	V		
VRSM	Surge Peak Reverse Voltage	650	V		
VR	DC Blocking Voltage	650	V		
IF	Forward Current	6	A	TC = 150°C	Fig.7
IFSM	Non-Repetitive Forward Surge Current	65	A	TC = 25°C, tp = 10ms Half Sine Wave	
IF,Max	Non-Repetitive Peak Forward Surge Current	520	A	TC=25°C, tP= 10 μs, Pulse	
IFRM	Repetitive Peak Forward Surge Current	40	A	TC = 25°C, tp = 10ms Half Sine Wave	
Ptot	Power Dissipation	111 48	W	TC = 25°C TC = 110°C	Fig.6
TJ,TST G	Operating Junction and Storage Temperature	-55 to175	°C		

Electrical Characteristics (T_J= 25°C unless otherwise specified)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
VF	Forward Voltage	1.4 1.75	1.7 2.0	V	IF = 6A, T _J = 25°C IF = 6A, T _J = 175°C	Fig.1
IR	Reverse Current	2 40	20 200	μA	VR = 650V, T _J = 25°C VR = 650V, T _J = 175°C	Fig.2
C	Total Capacitance	332 33 28	/	pF	VR=0V, T _J = 25°C, f=1MHz VR=200V, T _J = 25°C, f=1MHz VR=400V, T _J = 25°C, f = 1MHz	Fig.3
QC	Total Capacitive Charge	17	/	nC	VR = 400V, T _J = 25°C $Q_c = \int_0^{V_R} C(V) dV$	Fig.4
Ec	Capacitance Stored Energy	4.3	/	μJ	VR = 400V	Fig.5

Thermal Characteristics (T_J= 25°C unless otherwise specified)

Symbol	Parameter	Typ.	Unit	Note
RθJC	Thermal Resistance from Junction to Case	1.35	°C/W	Fig.8

Typical Feature Curve

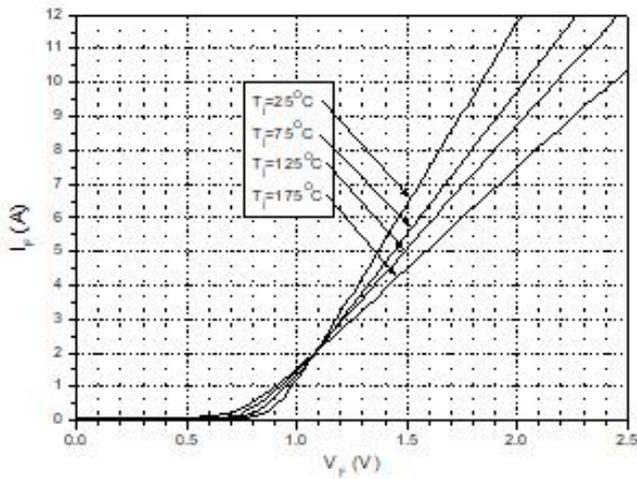


Figure 1. Forward Characteristics

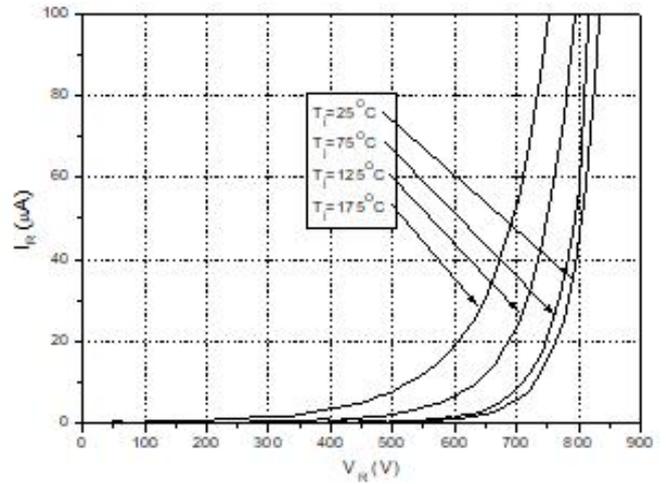


Figure 2. Reverse Characteristics

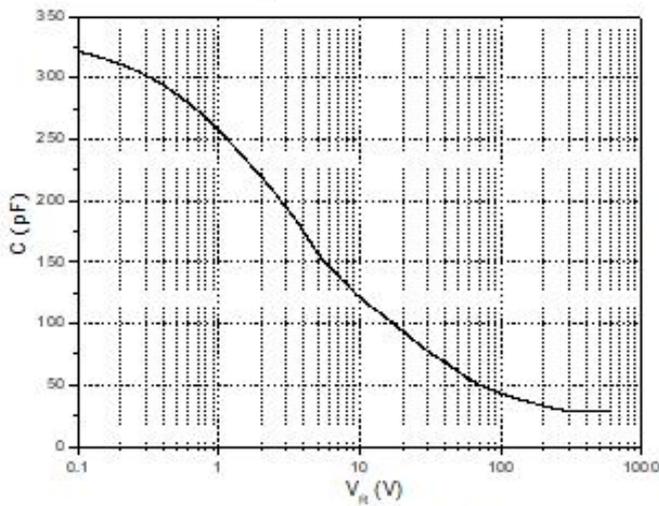


Figure 3. Capacitance vs. Reverse Voltage

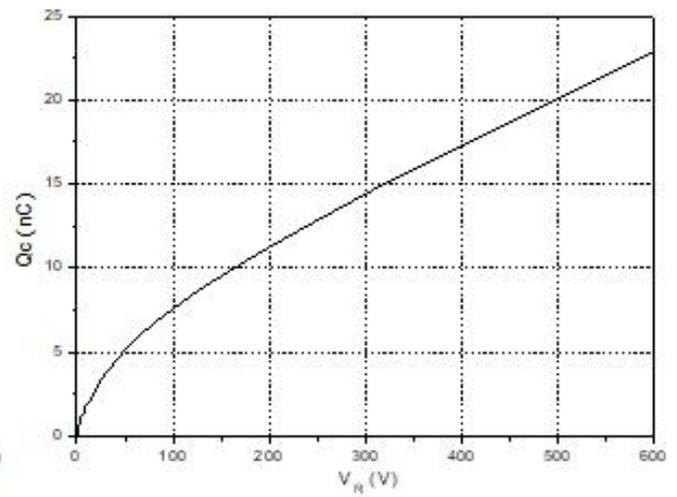


Figure 4. Total Capacitance Charge vs. Reverse Voltage

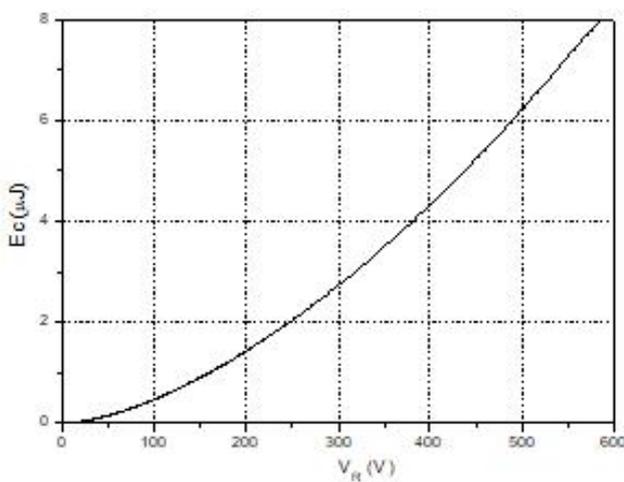


Figure 5. Capacitance Stored Energy

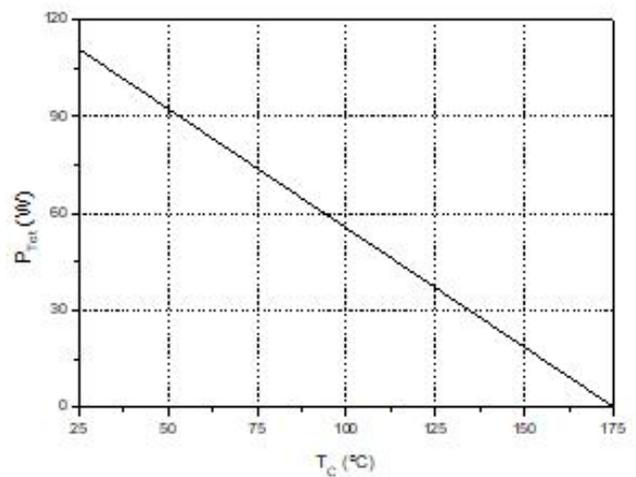


Figure 6. Power Derating

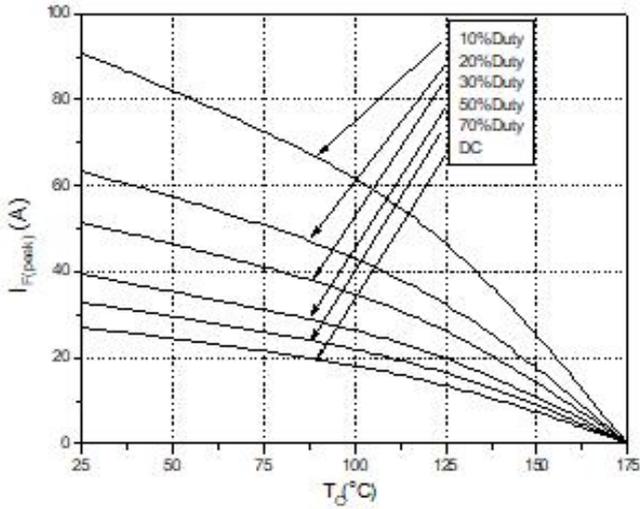


Figure 7. Current Derating

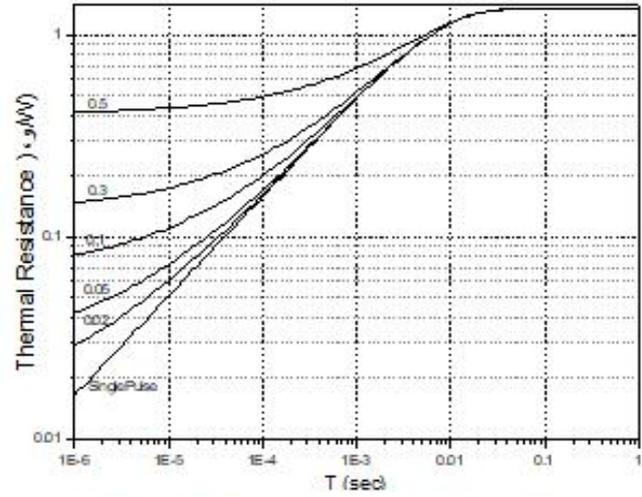
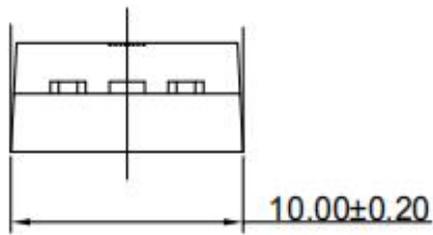
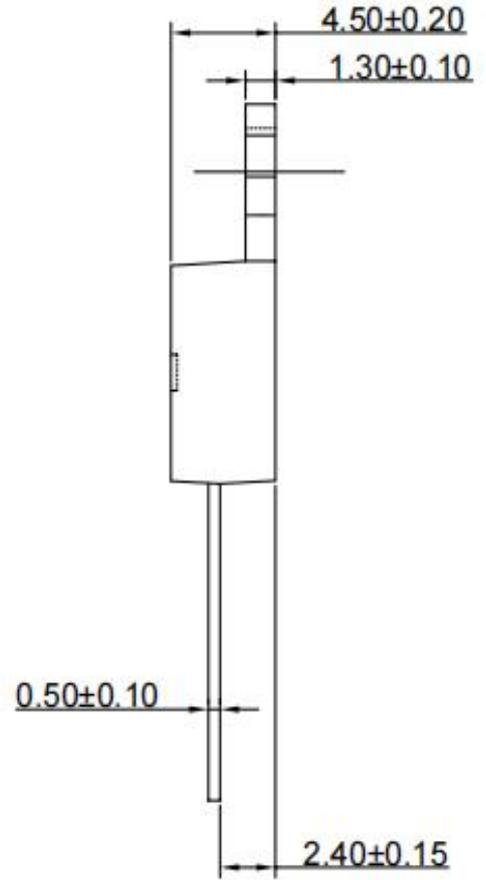
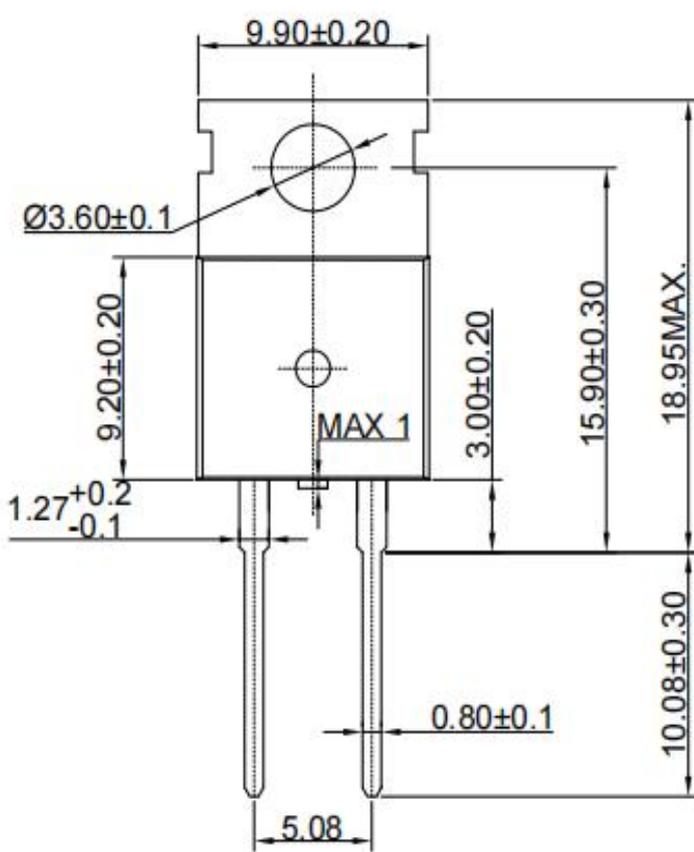


Figure 8. Transient Thermal Impedance

Package outline drawing(TO-220 Unit: mm)



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